#### Diffusion

Diffusion - Mass transport by atomic motion

#### Mechanisms

- •Gases & Liquids random (Brownian) motion
- •Solids vacancy diffusion or interstitial diffusion

Interdiffusion: In an alloy, atoms tend to migrate from regions of high conc. to regions of low conc.

Self-diffusion: In an elemental solid, atoms also migrate.

#### Interdiffusion



Label some atoms



After some time



#### **Diffusion mechanisms**

Conditions:

Vacancy Diffusion:

- atoms exchange with vacancies
- · applies to substitutional impurities atoms
- rate depends on:
  - --number of vacancies
  - --activation energy to exchange.

increasing elapsed time

#### **Diffusion simulation**

- Simulation of interdiffusion across an interface:
- Rate of substitutional diffusion depends on:
  -vacancy concentration
  -frequency of jumping.

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(Courtesy P.M. Anderson)

How do we quantify the amount or rate of diffusion?

Measured empirically

- Make thin film (membrane) of known surface area
- Impose concentration gradient
- Measure how fast atoms or molecules diffuse through the membrane

#### Steady-state diffusion





• Diffusion coefficient increases with increasing *T*.

## **Diffusion paths**



- materials w/secondary bonding
- smaller diffusing atoms
- lower density materials

- materials w/covalent bonding
- larger diffusing atoms
- higher density materials

## Engineering stress

- Tensile stress,  $\sigma\!\!:$ 



• Shear stress,  $\tau$ :



#### **Engineering strain**

• Tensile strain:



• Shear strain:



• Lateral strain:

## **Engineering strain**

• Modulus of Elasticity, *E*: (also known as Young's modulus)



#### Elastic properties of materials





#### **Plastic deformation**



# Yield strength, $\sigma_{\rm y}$



## Tensile strength, TS

• Maximum stress on engineering stress-strain curve.



- Metals: occurs when noticeable necking starts.
- Polymers: occurs when polymer backbone chains are aligned and about to break.

#### Ductility

• Plastic tensile strain at failure:



#### Toughness

- Energy to break a unit volume of material
- Approximate by the area under the stress-strain curve.



#### Hardness

- Resistance to permanently indenting the surface.
- Large hardness means:
  - --resistance to plastic deformation or cracking in compression.
  - --better wear properties.



		Shape of Indentation			Formula for
Test	Indenter	Side View	Top View	Load	Hardness Number <sup>a</sup>
Brinell	10-mm sphere of steel or tungsten carbide		_;=  d  ←	Р	$HB = \frac{2P}{\pi D[D - \sqrt{D^2 - d^2}]}$
Vickers microhardness	Diamond pyramid			Р	$HV = 1.854P/d_1^2$
Knoop microhardness	Diamond pyramid	<i>l/b</i> = 7.11 <i>b/t</i> = 4.00		Р	$\mathbf{HK} = 14.2P/l^2$
Rockwell and Superficial Rockwell	$\begin{cases} Diamond \\ cone \\ \frac{1}{18}, \frac{1}{8}, \frac{1}{4}, \frac{1}{2} \text{ in.} \\ diameter \\ steel spheres \end{cases}$			60 100 150 15 30 45	kg kg kg kg Superficial Rockwell kg

#### Table 6.5 Hardness Testing Techniques

<sup>a</sup> For the hardness formulas given, P (the applied load) is in kg, while D, d, d<sub>1</sub>, and l are all in mm.

Source: Adapted from H. W. Hayden, W. G. Moffatt, and J. Wulff, The Structure and Properties of Materials, Vol. III, Mechanical Behavior. Copyright © 1965 by John Wiley & Sons, New York. Reprinted by permission of John Wiley & Sons, Inc.

#### Dislocation and plastic deformation

• Cubic & hexagonal metals - plastic deformation by plastic shear or slip where one plane of atoms slides over adjacent plane by defect motion (dislocations).



Adapted from Fig. 7.1, *Callister 7e.* 

#### **Dislocation motion**



#### Deformation mechanisms



Adapted from Fig. 7.6, *Callister 7e.* 

#### Slip in single crystals

- Crystals slip due to a resolved shear stress,  $\tau_R$ .
- Applied tension can produce such a stress.



#### Critical resolved shear stress

- Condition for dislocation motion:
- Crystal orientation can make it easy or hard to move dislocation



#### Slip motion in polycrystals

- Stronger grain boundaries pin deformations
- Slip planes & directions  $(\lambda, \phi)$  change from one crystal to another.
- $\tau_R$  will vary from one crystal to another.
- The crystal with the largest  $\tau_{\text{R}}$  yields first.
- Other (less favorably oriented) crystals yield later.



Adapted from Fig. 7.10, *Callister 7e.* (Fig. 7.10 is courtesy of C. Brady, National Bureau of Standards [now the National Institute of Standards and Technology, Gaithersburg, MD].)

#### Strategies for strengthening: grain size reduction

- Grain boundaries are barriers to slip.
- Barrier "strength" increases with increasing angle of misorientation.
- Smaller grain size: more barriers to slip.



Adapted from Fig. 7.14, *Callister 7e.* (Fig. 7.14 is from *A Textbook of Materials Technology*, by Van Vlack, Pearson Education, Inc., Upper Saddle River, NJ.)

• Hall-Petch Equation:

#### Strategies for strengthening: solid solutions



Adapted from Fig. 7.4, *Callister 7e.* 

#### Effects of stress at dislocations



Strengthening by alloying



Adapted from Fig. 7.17, *Callister 7e.* 

Strengthening by alloying



## Strategies for strengthening: Cold work (%CW)

- Room temperature deformation.
- Common forming operations change the cross sectional area:



#### Impact of cold work

As cold work is increased

